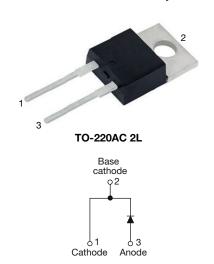


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HEXFRED®, Ultrafast Soft Recovery Diode, 6 A



PRIMARY CHARACTERISTICS								
I _{F(AV)}	6 A							
V_{R}	1200 V							
V _F at I _F	3.0 V							
t _{rr} typ.	26 ns							
T _J max.	150 °C							
Package	TO-220AC 2L							
Circuit configuration	Single							

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA06TB120 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 6 A continuous current, the VS-HFA06TB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the th portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA06TB120 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Cathode to anode voltage	V _R		1200	V						
Maximum continuous forward current	I _F	T _C = 100 °C	6							
Single pulse forward current	I _{FSM}		80	Α						
Maximum repetitive forward current	I _{FRM}		24							
Maximum namer discipation	D	T _C = 25 °C	62.5	14/						
Maximum power dissipation	P_{D}	T _C = 100 °C	25	W						
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C						



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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS					
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA	1200	-	-					
Maximum forward voltage	V _{FM}	I _F = 6.0 A	-	2.7	3.0	V				
		I _F = 12 A	-	3.5	3.9					
		I _F = 6.0 A, T _J = 125 °C	-	2.4	2.8					
Maximum reverse	I _{RM}	$V_R = V_R$ rated	-	0.26	5.0					
leakage current		$T_J = 125 ^{\circ}\text{C}, V_R = 0.8 ^{\circ}\text{X} ^{\circ}\text{V}_R ^{\circ}\text{rated}$ - 110		110	500	μΑ				
Junction capacitance	C _T	V _R = 200 V		9.0	14	pF				
Series inductance L _S Measured lead to lead 5 mm from		Measured lead to lead 5 mm from package body	-	8.0	-	nΗ				

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				UNITS		
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}$	A/μs, V _R = 30 V	-	26	-	ns		
Reverse recovery time	t _{rr1}	T _J = 25 °C		-	53	80			
	t _{rr2}	T _J = 125 °C		-	87	130			
Deale second and and	I _{RRM1}	T _J = 25 °C		-	4.4	8.0	A nC		
Peak recovery current	I _{RRM2}	T _J = 125 °C	I _F = 6.0 A dI _F /dt = 200 A/μs	-	5.0	9.0			
Reverse recovery charge	Q _{rr1}	T _J = 25 °C	V _R = 200 V	-	116	320			
neverse recovery charge	Q _{rr2}	T _J = 125 °C		-	233	585	110		
Peak rate of recovery current	dI _{(rec)M} /dt1	T _J = 25 °C		-	180	-	Λ/ι.ο		
during t _b	dI _{(rec)M} /dt2	T _J = 125 °C		-	100	-	A/µs		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL TEST CONDITIONS				MAX.	UNITS			
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C			
Thermal resistance, junction to case	R _{thJC}		-	-	2.0				
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	K/W			
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-				
Weight			-	2.0	-	g			
vveigni			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style 2L TO-220AC	HFA06TB120						



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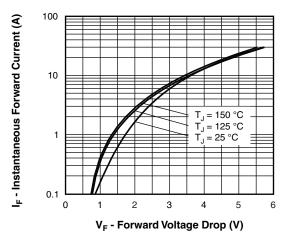


Fig. 1 - Typical Forward Voltage Drop Characteristics

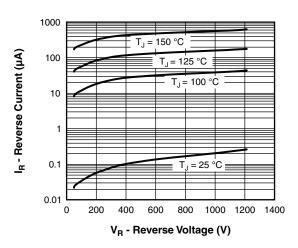


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

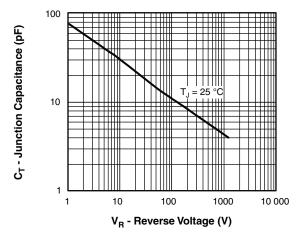


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

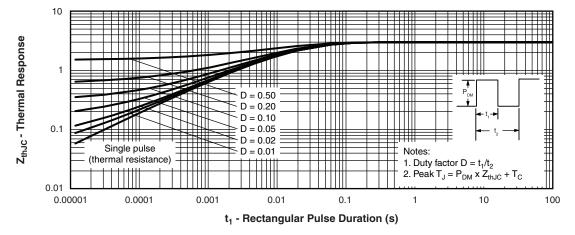


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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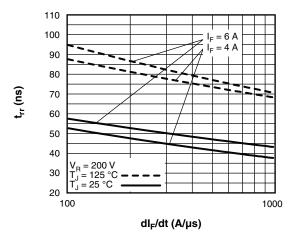


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

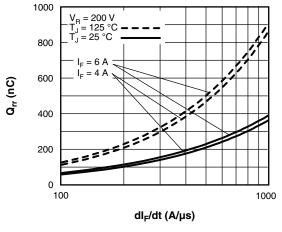


Fig. 7 - Typical Stored Charge vs. dl_E/dt

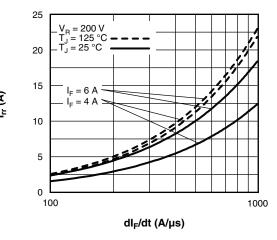


Fig. 6 - Typical Recovery Current vs. dl_F/dt

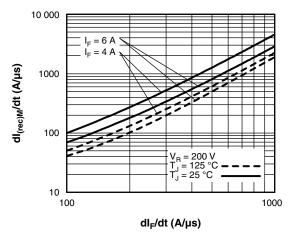
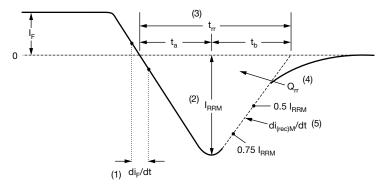


Fig. 8 - Typical dl_{(rec)M}/dt vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_{rr}$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

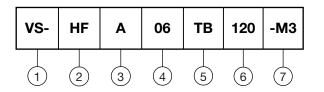
Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - HEXFRED® family

3 - Electron irradiated

Current rating (06 = 6 A)

5 - Package:

TB = 2L TO-220AC

6 - Voltage rating (120 = 1200 V)

7 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

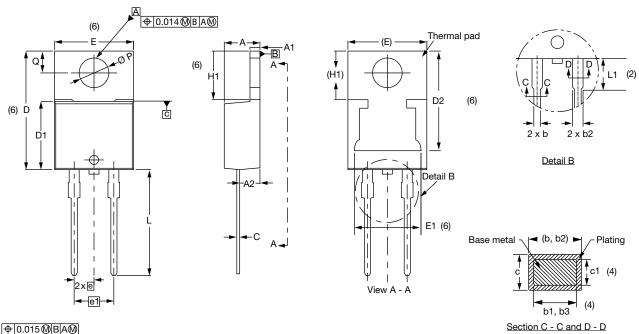
ORDERING INFORMATION (Example)									
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION									
VS-HFA06TB120-M3	50	Antistatic plastic tube							

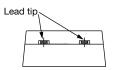
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96156</u>							
Part marking information	www.vishay.com/doc?95391						

Vishay Semiconductors

TO-220AC 2L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•		•	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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